

Monolithic Linear IC

SANYO

No. 3979

LA1883M

Single-chip FM/AM Tuner for Car Radio and Home Stereo Equipment

OVERVIEW

The LA1883M is a single-chip stereo FM/AM tuner system IC for use in car radio and home stereo equipment. It features higher performance and 30% fewer external components than current devices.

The LA1883M is a basic FM/AM tuner block on a single chip. It comprises FM front end, FM IF, MPX, noise canceller, AM and AM/FM switch.

The LA1883M operates from a 7.5 to 9.2 V supply and is available in 64-pin QIPs.

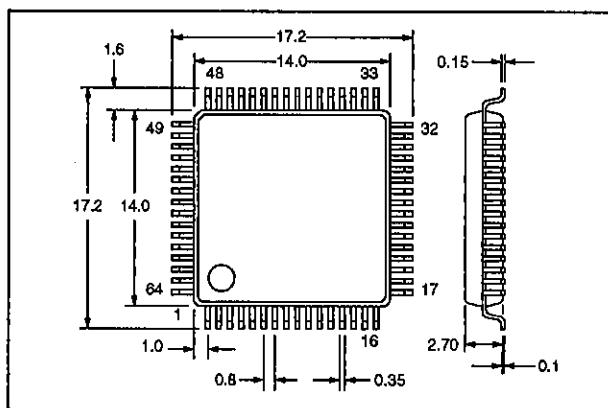
FEATURES

- Single-chip stereo FM/AM tuner
- FM front end, FM IF, MPX, noise canceller, AM and FM/AM switch
- Higher performance and 30% fewer external components than current devices.
- High FM front end to FM IF stage isolation
- 7.5 to 9.2 V supply
- 64-pin QIP

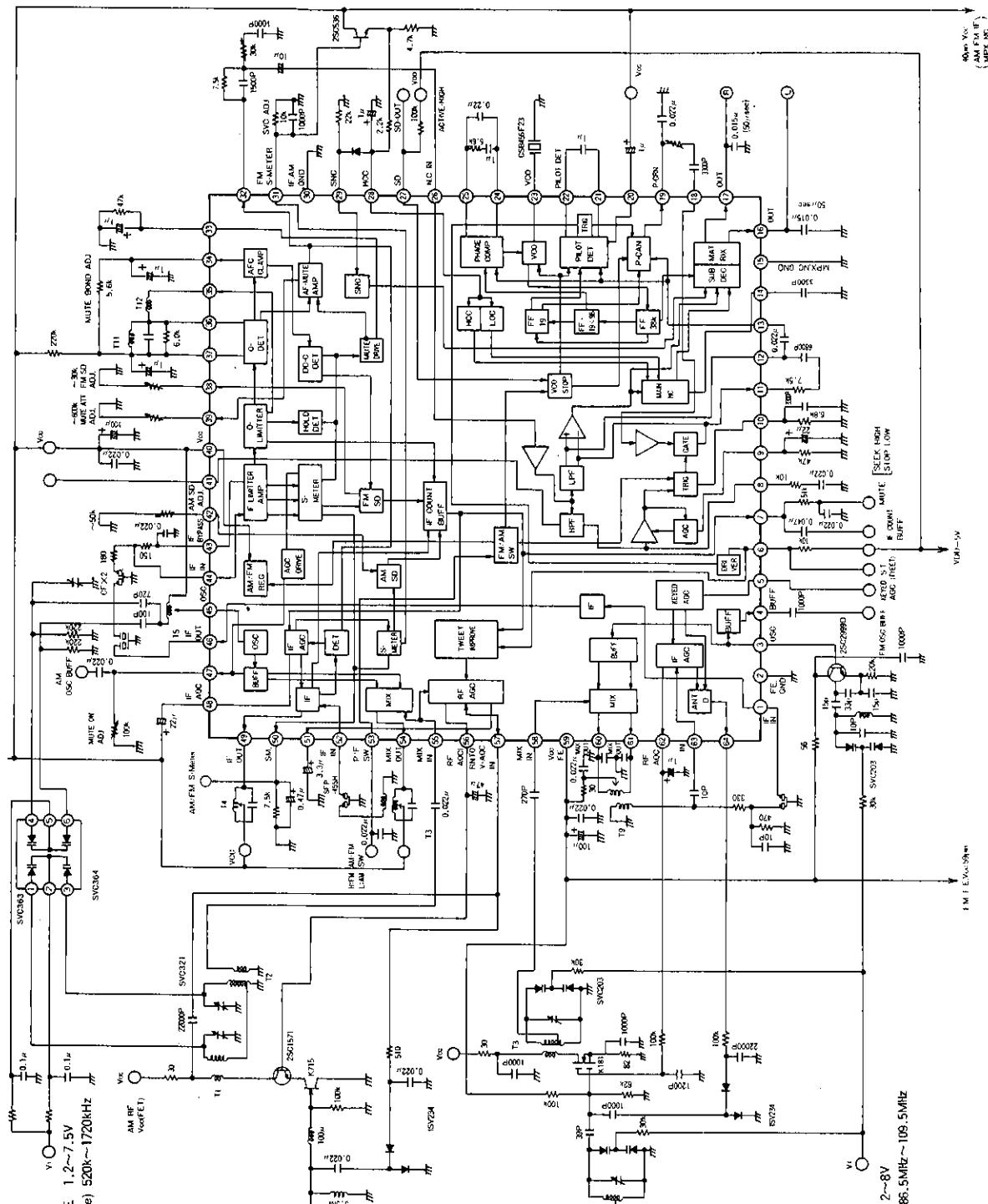
PACKAGE DIMENSIONS

Unit: mm

3159-QIP64E



BLOCK DIAGRAM



Unit (resistance: Ω , capacitance: F)

SPECIFICATIONS**Absolute Maximum Ratings**

Parameter	Symbol	Rating	Unit
Supply voltage	V _{CC}	9.5	V
Power dissipation	P _D	950	mW
Operating temperature range	T _{OPR}	-30 to 85	°C
Storage temperature range	T _{STG}	-40 to 150	°C

Recommended Operating ConditionsT_a = 25 °C

Parameter	Symbol	Rating	Unit
Supply voltage	V _{CC}	8.5	V
Supply voltage range	V _{CC}	7.5 to 9.2	V
STEREO INJ supply voltage	V _{CC STEREO INJ}	5	V

Electrical Characteristics**FM IF**V_{CC} = 8.5 V, T_a = 25 °C, f_C = 10.7 MHz

Parameter	Symbol	Condition	Rating			Unit
			min	typ	max	
Demodulator output voltage	V _{OFM}	f _m = 1 kHz, 100% modulation, V _I = 80 dBμ	180	280	380	mV
Channel balance	CB	f _m = 1 kHz, 100% modulation, V _I = 80 dBμ	-1	0	1	dB
FM total harmonic distortion	THD _{FM}	f = 1 kHz, 100% modulation, V _I = 80 dBμ	-	0.5	1.2	%
Signal-to-noise ratio	S/N _{FM IF}	f = 1 kHz, 100% modulation, V _I = 80 dBμ	68	75	-	dB
AM suppression ratio	AMR	f = 1 kHz, f _m = 1 kHz, 30% AM modulation, V _I = 80 dBμ	56	69	-	dB
Muting attenuation	α _{MUTE}	f = 1 kHz, V _I = 80 dBμ. V ₃₃ changed from 0 to 2 V.	5	10	15	dB
		f = 1 kHz, V _I = 80 dBμ. V ₃₃ changed from 0 to 4 V.	19	24	29	
Separation	SEP	See note 2.	35	45	-	dB
Stereo LED turn-ON pilot tone modulation	ST _{ON}	V ₆ < 1.5 V	2.5	3.7	6.6	%

Parameter	Symbol	Condition	Rating			Unit
			min	typ	max	
Stereo LED turn-OFF pilot tone modulation	S_{TOFF}	$V_6 < 3.5$ V	1.5	2.7	-	%
Main channel total harmonic distortion	THD_{main}	See note 2.	-	0.4	1.5	%
Pilot signal cancellation level	P_{CAN}	10% pilot signal, $V_i = 80$ dB μ , Pilot-level leakage DIN-AUDIO measurement	15	22	-	dB
SNC output voltage	V_{OSUS}	$V_i = 80$ dB μ , $V_{31} = 0.1$ V. See note 2.	-	-	5	mV
SNC output attenuation	α_{SNC}	$V_i = 80$ dB μ . V_{31} changed from 3.0 to 0.6 V. See note 2.	0	4	8	dB
HCC output attenuation	α_{HCC}	$V_i = 80$ dB μ , $f = 10$ kHz. V_{28} changed from 3.0 to 0.6 V. See note 2.	0.5	4.5	8.5	dB
		$V_i = 80$ dB μ , $f = 10$ kHz. V_{28} changed from 3.0 to 0.1 V. See note 2.	20	24	28	
Input -3 dB limiting voltage	V_{ILIM}	Referred to $V_i = 80$ dB μ .	33	40	47	dB μ
Muting sensitivity	V_{IMUTE}	Unmodulated signal, $V_{33} = 2$ V	27	35	43	dB μ
SD sensitivity	$SD_{SEN\ MPX}$	Unmodulated signal. IF count buffer is ON ($V > 100$ mV).	60	72	84	dB μ
		Unmodulated signal. SD is ON.	60	72	84	
IF count buffer output voltage	$V_{IF\ BUFF\ FM}$	Unmodulated input and output, $V_{FM\ IF} = 100$ dB μ	170	260	400	mV
S-meter output voltage	$V_{SM\ FM}$	No signal	0	0.4	1.0	V
		$V_i = 50$ dB μ	1.0	1.9	3.0	
		$V_i = 70$ dB μ	1.9	3.4	5.5	
		$V_i = 100$ dB μ	3.3	5.2	6.9	
Muting bandwidth	BW_{MUTE}	$V_i = 100$ dB μ , $V_{33} = 2$ V unmodulated wideband signal	150	230	330	kHz

Notes

1. Mounted in Yamaichi Electrical Industries' IC-51-0644-824 or KS8277 IC socket
2. f_i comprises 90% left and right signals, and 10% pilot signal.

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FM front end

$V_{CC} = 8.5 \text{ V}$, $T_a = 25^\circ\text{C}$

Parameter	Symbol	Condition	Rating			Unit
			min	typ	max	
RF AGC turn-ON input voltage	V_{AGC}	$V_{64} = 0.7 \text{ V}$	65	72	79	$\text{dB}\mu$
Conversion voltage gain	A_V	$V_{MIX IN} = 70 \text{ dB}\mu$ at 98 MHz with no modulation	74	118	187	mV
OSC BUFF output voltage	$V_{OSC\ BUFF\ FM}$	No signal, $f_{osc} = 108.7 \text{ MHz}$, $V_t = 4.6 \text{ V}$	130	200	270	mV
FM section quiescent supply current	I_{CCFOM}	No signal. $I_{40} + I_{49} + I_{54} + I_{60} + I_{61}$	54	77	95	mA

Noise canceller

$V_{CC} = 8.5 \text{ V}$, $T_a = 25^\circ\text{C}$

Parameter	Symbol	Condition	Rating			Unit
			min	typ	max	
Gate time	τ_{GATE}	$V_{NC\ IN} = 100 \text{ mV}$ peak at $f = 1 \text{ kHz}$, $1 \mu\text{s}$ pulse	15	25	35	μs
Noise sensitivity	N_{SEN}	1 kHz, $1 \mu\text{s}$ pulse input level when noise canceller is ON	-	-	30	mV_p

AM

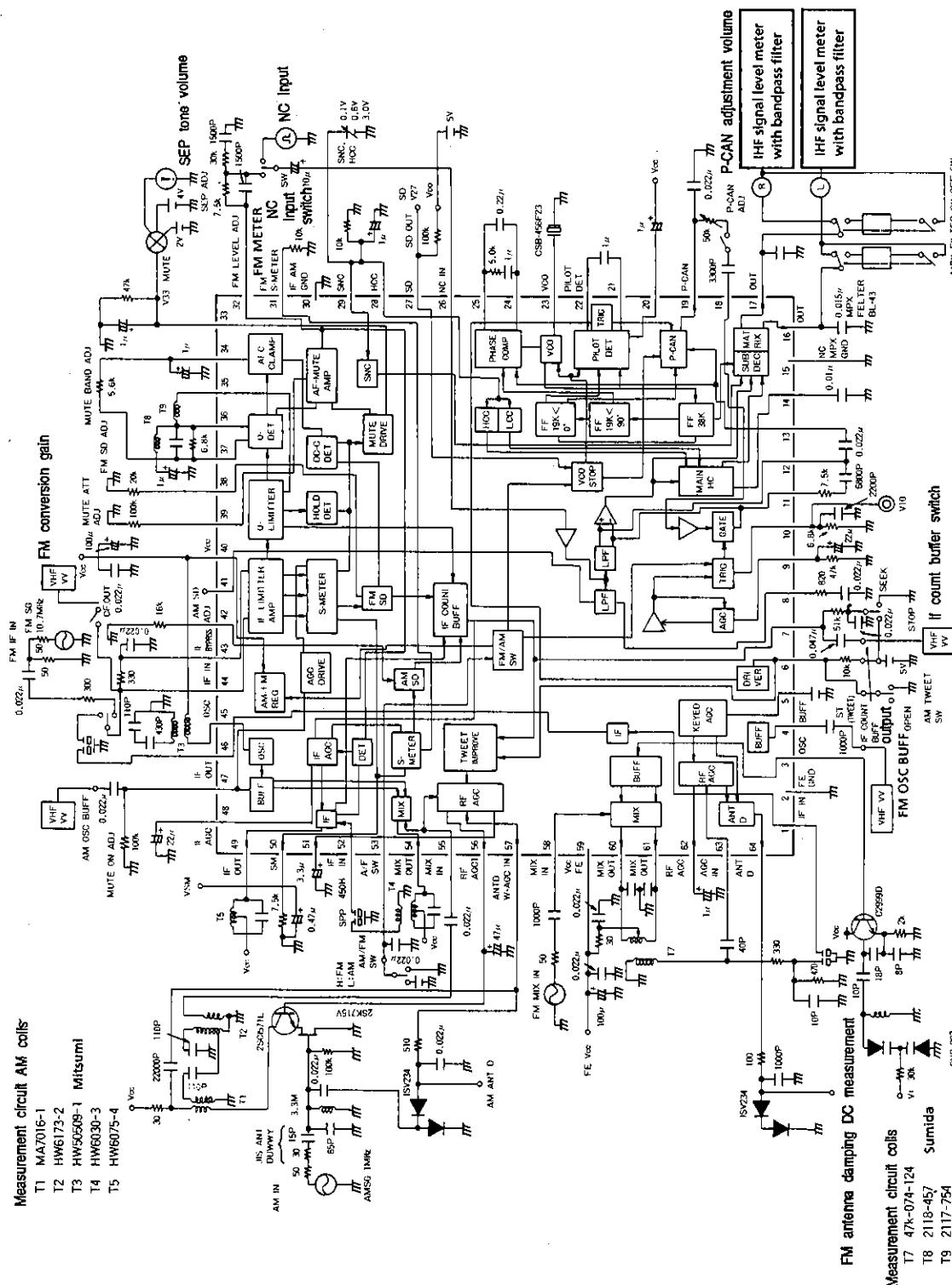
$V_{CC} = 8.5 \text{ V}$, $T_a = 25^\circ\text{C}$, $f_{AM\ ANT} = 1 \text{ MHz}$ unless otherwise noted

Parameter	Symbol	Condition	Rating			Unit
			min	typ	max	
Usable sensitivity	S	$V_{AM\ ANT} = 27 \text{ dB}\mu$, $f_m = 1 \text{ kHz}$, 30% modulation	16	20	-	dB
Detector output voltage	V_{OAM}	$V_{AM\ ANT} = 74 \text{ dB}\mu$, $f_m = 1 \text{ kHz}$, 30% modulation	85	120	170	mV
AGC figure-of-merit	V_{AGCFOM}	Referred to $V_{AM\ ANT} = 74 \text{ dB}\mu$, change in input required for output to fall 10 dB	52	57	62	dB
Signal-to-noise ratio	S/N_{AM}	$V_{AM\ ANT} = 74 \text{ dB}\mu$, $f_m = 1 \text{ kHz}$, 30% modulation	45	50	-	dB
Total harmonic distortion	THD_{AM}	$V_{AM\ ANT} = 74 \text{ dB}\mu$, $f_m = 1 \text{ kHz}$, 80% modulation	-	0.4	1.0	%
S-meter output voltage	$V_{SM\ AM}$	No signal	-	0	0.3	V
		$V_{AM\ ANT} = 100 \text{ dB}\mu$, unmodulated	3.3	4.7	7.0	
OSC BUFF output voltage	$V_{OSC\ BUFF\ AM}$	No signal	310	370	-	mV

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Parameter	Symbol	Condition	Rating			Unit
			min	typ	max	
Wideband-AGC sensitivity	W-AGC _{SEN}	f _{AM ANT} = 1.4 MHz, V _{S7} = 0.7 V	93	99	105	dB μ
SD antenna input level sensitivity	SD _{SEN AM}	IF count output is ON.	23	30	37	dB μ
		SD is ON.	23	30	37	
Tweet reduction circuit antenna input level sensitivity	Tweet _{SEN}	N ₆ = 0 V, AGC ON input	50	56	62	dB μ
IF BUFF output voltage	V _{IF BUFF AM}	V _{AM ANT} = 74 dB μ , unmodulated	200	260	-	mV

Measurement Circuit



Unit (resistance: Ω , capacitance: F)

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